

250V N-CHANNEL ENHANCEMENT MODE MOSFET

SUMMARY

$V_{(BR)DSS}=250V$; $R_{DS(ON)}=8.5\Omega$; $I_D=240mA$

DESCRIPTION

This 250V enhancement mode N-channel MOSFET provides users with a competitive specification offering efficient power handling capability, high impedance and is free from thermal runaway and thermally induced secondary breakdown. Applications benefiting from this device include a variety of Telecom and general high voltage circuits.

SOT223 and SOT23-6 versions are also available.

FEATURES

- High voltage
- Low on-resistance
- Fast switching speed
- Low gate drive
- Low threshold
- Complementary P-channel Type ZVP4525G
- SOT223 package

APPLICATIONS

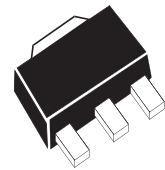
- Earth Recall and dialling switches
- Electronic hook switches
- High Voltage Power MOSFET Drivers
- Telecom call routers
- Solid state relays

ORDERING INFORMATION

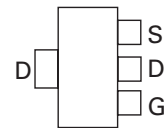
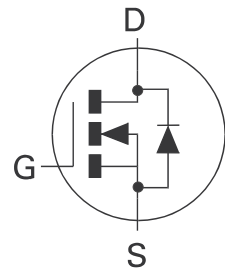
| DEVICE | REEL SIZE (inches) | TAPE WIDTH (mm) | QUANTITY PER REEL |
|------------|--------------------|-----------------|-------------------|
| ZVN4525ZTA | 7 | 8mm embossed | 1000 units |

DEVICE MARKING

N52



SOT89



Top View

ZVN4525Z

ABSOLUTE MAXIMUM RATINGS.

| PARAMETER | SYMBOL | LIMIT | UNIT |
|---|----------------|-------------|----------------|
| Drain-Source Voltage | V_{DSS} | 250 | V |
| Gate Source Voltage | V_{GS} | ± 40 | V |
| Continuous Drain Current ($V_{GS}=10V$; $T_A=25^\circ C$)(a) ($V_{GS}=10V$; $T_A=70^\circ C$)(a) | I_D I_D | 240 192 | mA mA |
| Pulsed Drain Current (c) | I_{DM} | 1.44 | A |
| Continuous Source Current (Body Diode) | I_S | 1.1 | A |
| Pulsed Source Current (Body Diode) | I_{SM} | 1.44 | A |
| Power Dissipation at $T_A=25^\circ C$ (a) | P_D | 1.2 | W |
| Linear Derating Factor | | 9.6 | mW/ $^\circ C$ |
| Operating and Storage Temperature Range | $T_j; T_{stg}$ | -55 to +150 | $^\circ C$ |

THERMAL RESISTANCE

| PARAMETER | SYMBOL | VALUE | UNIT |
|-------------------------|-----------------|-------|--------------|
| Junction to Ambient (a) | $R_{\theta JA}$ | 103 | $^\circ C/W$ |
| Junction to Ambient (b) | $R_{\theta JA}$ | 50 | $^\circ C/W$ |

NOTES

(a) For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions

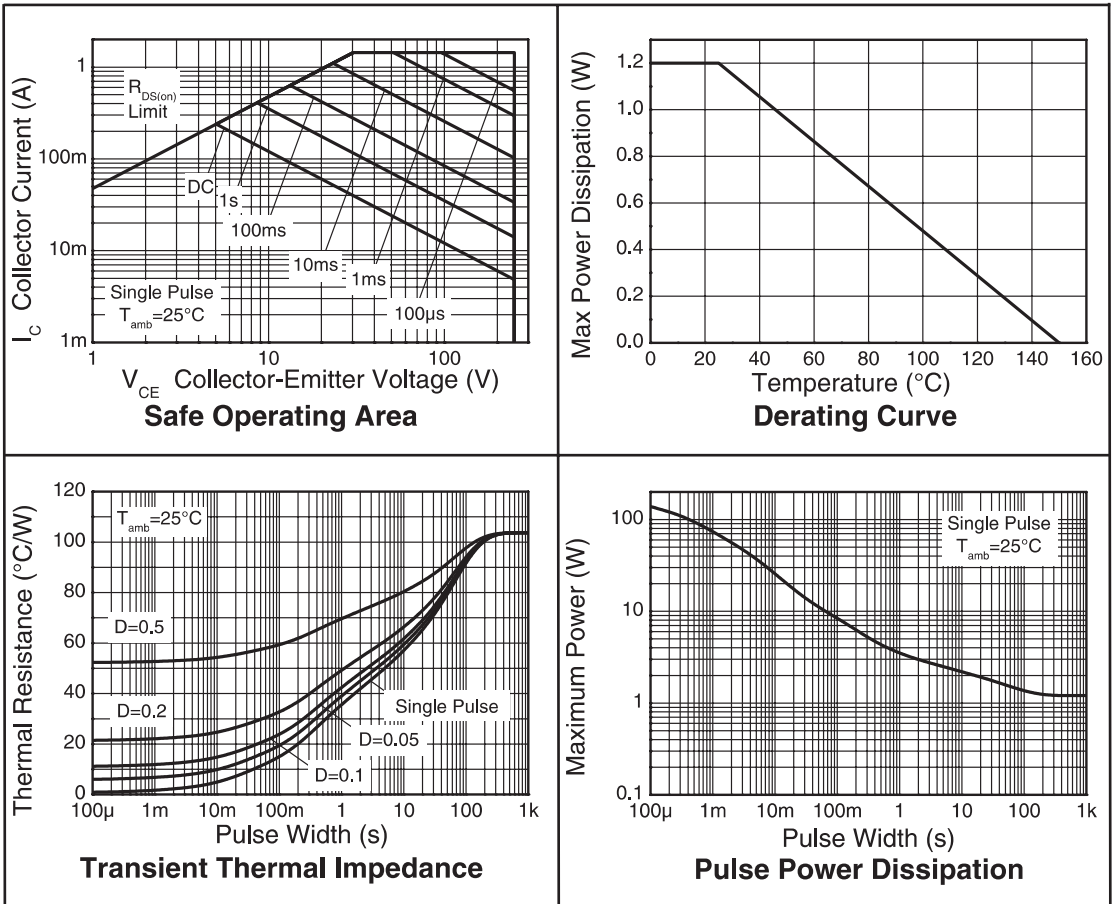
(b) For a device surface mounted on FR4 PCB measured at $t \leq 5$ secs.

(c) Repetitive rating - pulse width limited by maximum junction temperature. Refer to Transient Thermal

NB High Voltage Applications

For high voltage applications, the appropriate industry sector guidelines should be considered with regard to voltage spacing between conductors.

CHARACTERISTICS



ZVN4525Z

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated).

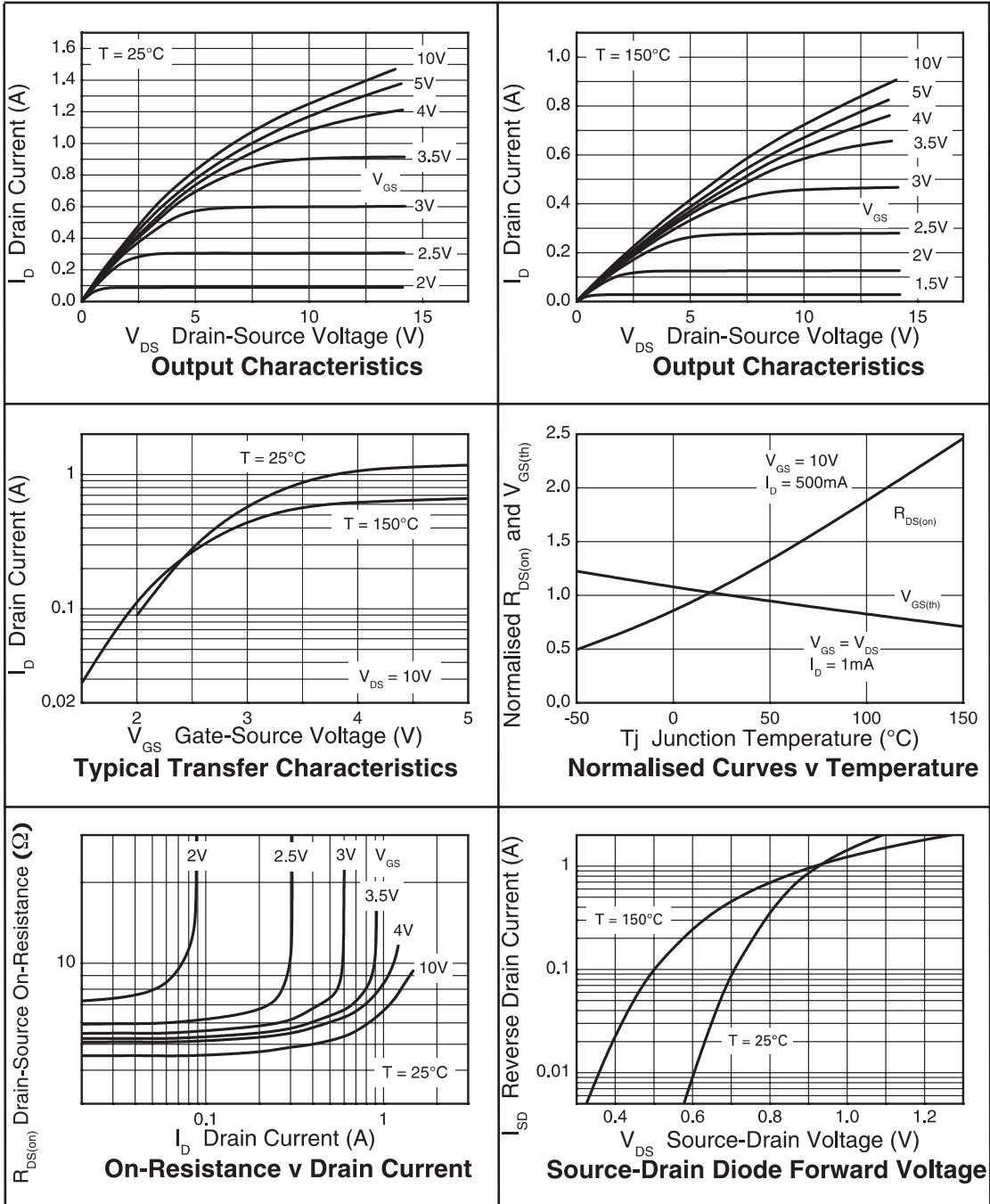
| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNI T | CONDITIONS. |
|---|---------------|------|-------------------|-------------------|----------|--|
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | 250 | 285 | | V | $I_D=1\text{mA}, V_{GS}=0\text{V}$ |
| Zero Gate Voltage Drain Current | I_{DSS} | | 35 | 500 | nA | $V_{DS}=250\text{V}, V_{GS}=0\text{V}$ |
| Gate-Body Leakage | I_{GSS} | | ± 1 | ± 100 | nA | $V_{GS}=\pm 40\text{V}, V_{DS}=0\text{V}$ |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | 0.8 | 1.4 | 1.8 | V | $I_D=1\text{mA}, V_{DS}=V_{GS}$ |
| Static Drain-Source On-State Resistance (1) | $R_{DS(on)}$ | | 5.6 5.9 6.4 | 8.5 9.0 9.5 | Ω | $V_{GS}=10\text{V}, I_D=500\text{mA}$ $V_{GS}=4.5\text{V}, I_D=360\text{mA}$ $V_{GS}=2.4\text{V}, I_D=20\text{mA}$ |
| Forward Transconductance (3) | g_{fs} | 0.3 | 475 | | S | $V_{DS}=10\text{V}, I_D=0.3\text{A}$ |
| DYNAMIC (3) | | | | | | |
| Input Capacitance | C_{iss} | | 72 | | pF | $V_{DS}=25\text{V}, V_{GS}=0\text{V},$ $f=1\text{MHz}$ |
| Output Capacitance | C_{oss} | | 11 | | pF | |
| Reverse Transfer Capacitance | C_{rss} | | 3.6 | | pF | |
| SWITCHING(2) (3) | | | | | | |
| Turn-On Delay Time | $t_{d(on)}$ | | 1.25 | | ns | $V_{DD}=50\text{V}, I_D=200\text{mA}$ $R_G=6.0\Omega, R_D=4.4\Omega$ (refer to test circuit) |
| Rise Time | t_r | | 1.70 | | ns | |
| Turn-Off Delay Time | $t_{d(off)}$ | | 11.40 | | ns | |
| Fall Time | t_f | | 3.50 | | ns | |
| Total Gate Charge | Q_g | | 2.6 | 3.65 | nC | $V_{DS}=25\text{V}, V_{GS}=10\text{V},$ $I_D=360\text{mA}$ (refer to test circuit) |
| Gate-Source Charge | Q_{gs} | | 0.2 | 0.28 | nC | |
| Gate Drain Charge | Q_{gd} | | 0.5 | 0.70 | nC | |
| SOURCE-DRAIN DIODE | | | | | | |
| Diode Forward Voltage (1) | V_{SD} | | | 0.97 | V | $T_j=25^{\circ}\text{C}, I_S=360\text{mA},$ $V_{GS}=0\text{V}$ |
| Reverse Recovery Time (3) | t_{rr} | | 186 | 260 | ns | $T_j=25^{\circ}\text{C}, I_F=360\text{mA},$ $di/dt=100\text{A}/\mu\text{s}$ |
| Reverse Recovery Charge (3) | Q_{rr} | | 34 | 48 | nC | |

(1) Measured under pulsed conditions. Width=300 μs . Duty cycle $\leq 2\%$.

(2) Switching characteristics are independent of operating junction temperature.

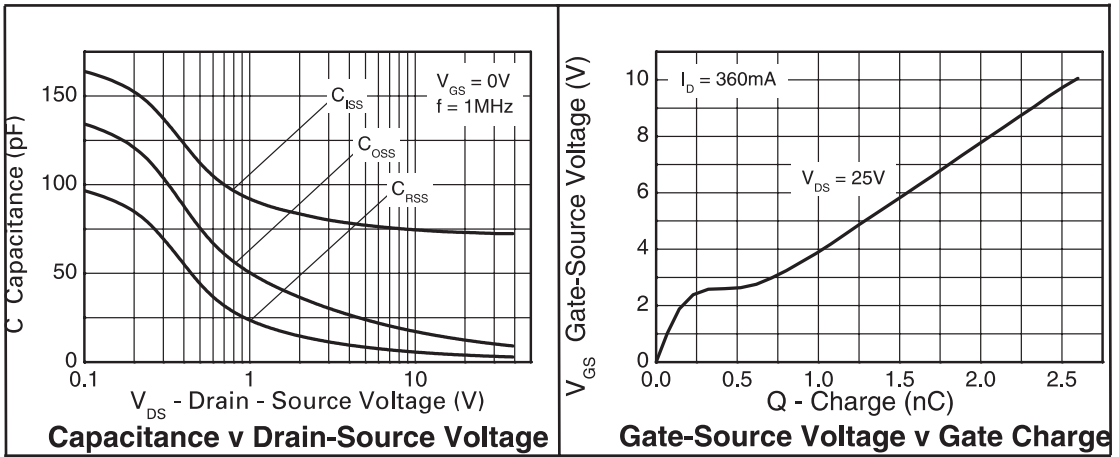
(3) For design aid only, not subject to production testing.

TYPICAL CHARACTERISTICS

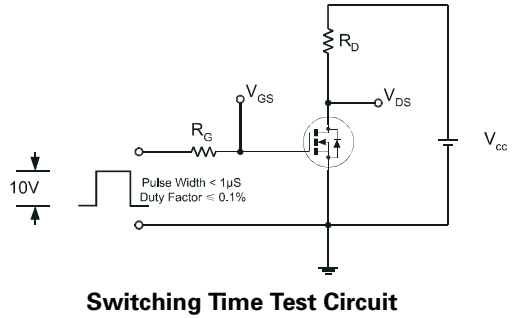
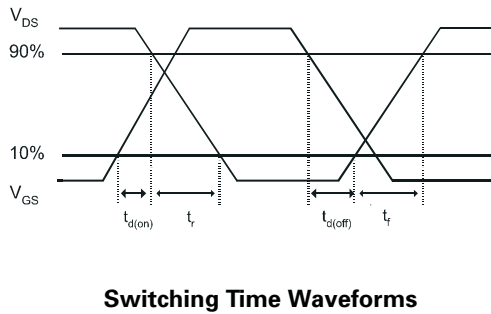
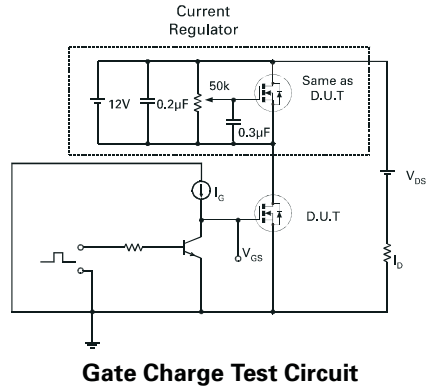
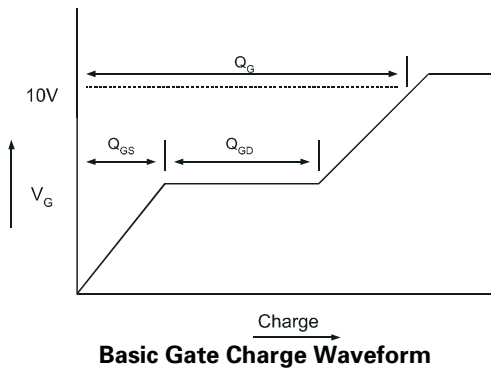


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CHARACTERISTICS



CHARACTERISTICS

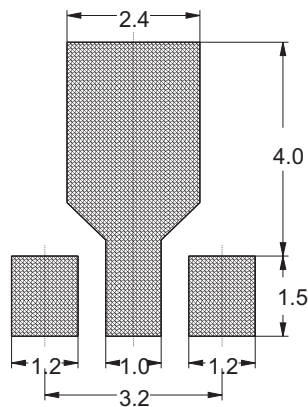


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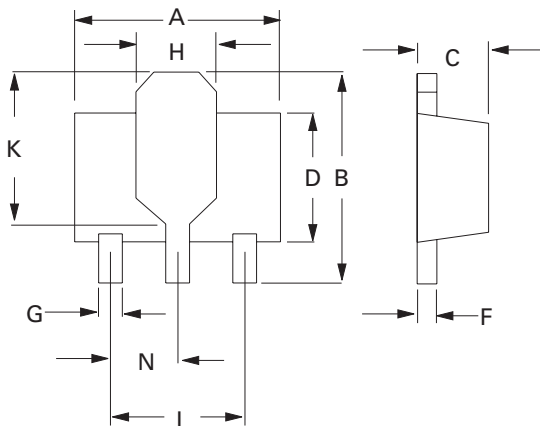
PACKAGE DIMENSIONS

| Dim | Millimeters | | Inches | |
|-----|-------------|------|--------|-------|
| | Min | Max | Min | Max |
| A | 4.40 | 4.6 | 0.173 | 0.181 |
| B | 3.75 | 4.25 | 0.150 | 0.167 |
| C | 1.40 | 1.6 | 0.550 | 0.630 |
| D | - | 2.6 | - | 0.102 |
| F | 0.28 | 0.45 | 0.011 | 0.018 |
| G | 0.38 | 0.55 | 0.015 | 0.022 |
| H | 1.5 | 1.80 | 0.060 | 0.072 |
| K | 2.6 | 2.85 | 0.102 | 0.112 |
| L | 2.90 | 3.10 | 0.114 | 0.122 |
| N | 1.4 | 1.60 | 0.055 | 0.063 |

PAD LAYOUT DETAILS



SOT89 pattern.
Minimum Pad Size (dimensions in mm)



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